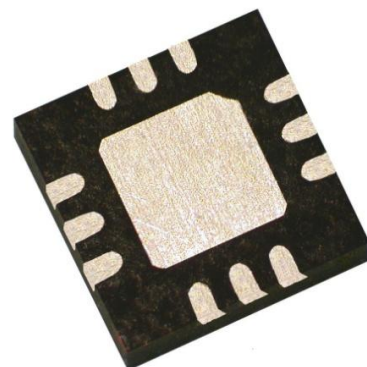


HRF-SW1000

SPDT Absorptive RF Switch DC To 4GHz Operation

The Honeywell HRF-SW1000 is a high performance single pole double throw (SPDT) absorptive RF switch ideal for use in wireless base station and handset applications that require minimum power and minimum insertion loss.

The HRF-SW1000 is manufactured with Honeywell's patented Silicon On Insulator (SOI) CMOS technology, which provides the performance of GaAs with the economy and integration capabilities of conventional CMOS technology. These switches are DC coupled to improve lower operating frequency, frequency response and reduce the number of DC bias points required.



FEATURES

HRF-SW1000 in VQFN Package

- Typical High Isolation Of > 42 dB @ 2 GHz
- Typical Low Insertion Loss Of 1.2dB @ 2 GHz
- Integrated CMOS Control Logic
- DC-coupled, bi-directional RF Path
- Single Positive Supply Voltage
- Ultra Small VQFN Packaging
- Impedance matched for 50 Ohm systems
- Lead-free, RoHS compliant and halogen-free

RF ELECTRICAL SPECIFICATIONS @ + 25°C

Results @ $V_{DD} = 5.0 \pm 10\%$, $V_{SS} = 0$ unless otherwise stated, $Z_0 = 50$ Ohms
Contact Honeywell for relative performance at other supply configurations

Parameter	Test Condition	Frequency	Minimum	Typical	Maximum	Units
Insertion Loss		0.5 GHz		0.9	1.4	dB
		2.0 GHz		1.2	1.6	dB
		3.0 GHz		1.7	2.2	dB
Isolation		0.5 GHz	52	55		dB
		2.0 GHz	42	45		dB
		3.0 GHz	36	41		dB
Return Loss			-15	-20		dB
Input P1dB	$V_{SS} = \text{Gnd}$ $V_{SS} = -5V$	1.0 GHz		17		dBm
		1.0 GHz		27		dBm
Input IP3	Two-Tone Inputs, up to + 5 dBm $V_{SS} = \text{Gnd}$ $V_{SS} = -5V$	2.0 GHz		35		dBm
		2.0 GHz		37		dBm
Trise, Tfall Ton, Toff	10% To 90%			10		ns
	50% Cntl To 90% / 10%RF			20		ns

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DC ELECTRICAL SPECIFICATIONS @ + 25°C

Parameter	Minimum	Typical	Maximum	Units
V _{DD}	3.3 ¹	5.0	5.5	V
V _{SS}	-5.0			V
I _{DD}		<5	35	uA
CMOS Logic Level (0)	0		0.8	V
CMOS Logic Level (1)	V _{DD} - 0.8		V _{DD}	V
Input Leakage Current			10	uA

Note 1, the performance curves are for V_{DD} = +5.0 +/- 10%

ABSOLUTE MAXIMUM RATINGS¹

Parameter	Absolute Maximum	Units
V _{DD}	+6.0	V
V _{SS}	-5.5	V
Vin Digital Logic 0	-0.6	V
Vin Digital Logic 1	V _{DD} + 0.6	V
Input Power	> 35	dBm
ESD Voltage ²	400	V
Moisture Sensitivity Level	Level 3 @ 260°C	
Operating Temperature Range	-40 to +85	°C
Storage Temperature Range	-65 to +125	°C

Note 1 - Operation of this device beyond any of these parameters may cause permanent damage.

Note 2 - Although the HRF-SW1000 contains ESD protection circuitry on all digital inputs, precautions should be taken to ensure that the Absolute Maximum Ratings are not exceeded.

Latch-Up: Unlike conventional CMOS digital switches, Honeywell's HRF-SW1000 is immune to latch-up.

TRUTH TABLE

Switch Control	RF Output 1	RF Output 2
0	RF INPUT	
1		RF INPUT

"0" = CMOS Low, "1" = CMOS High

PIN CONFIGURATIONS

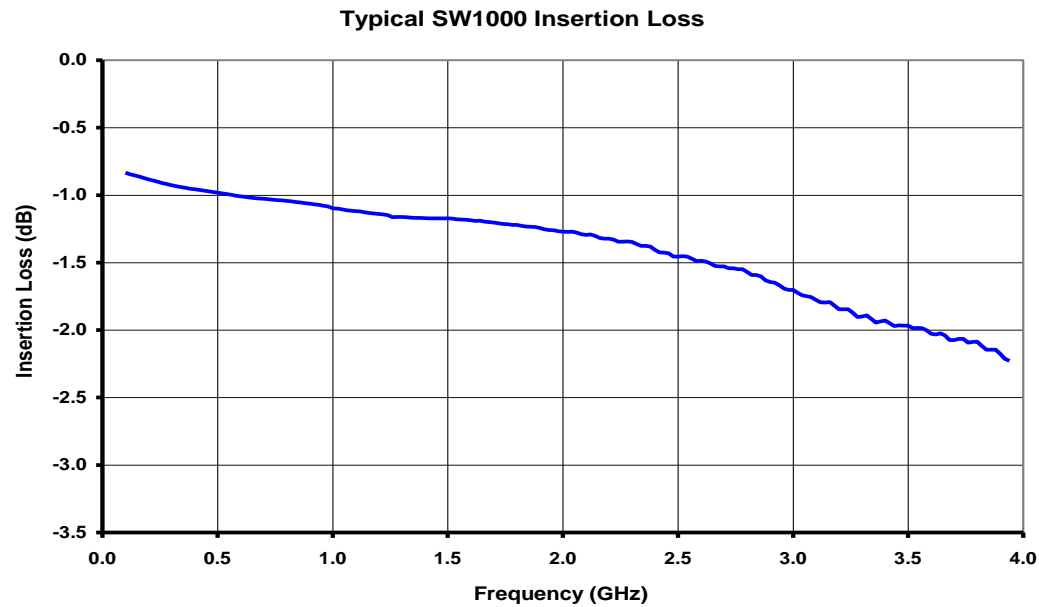
Pin	Function	Pin	Function
1	GROUND	7	GROUND
2	RF OUT 2	8	RF OUT 1
3	GROUND	9	GROUND
4	VDD	10	GROUND
5	SWITCH CONTROL	11	RF IN
6	VSS	12	GROUND

Note: Bottom ground plate must be grounded for proper RF performance.

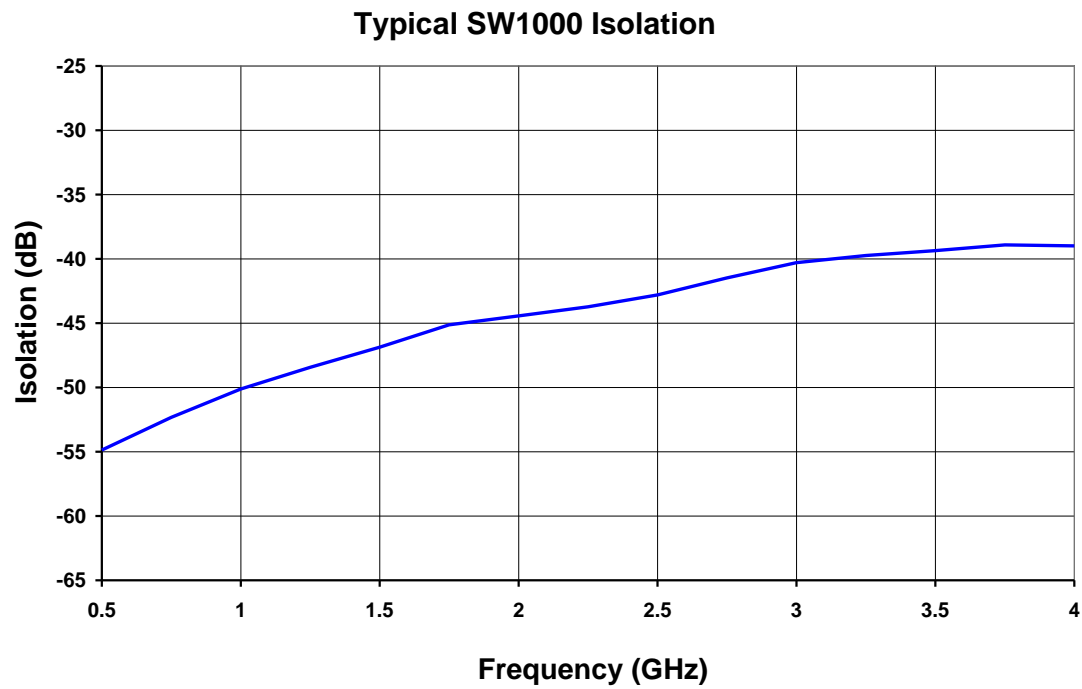
HRF-SW1000

PERFORMANCE CURVES

Insertion Loss

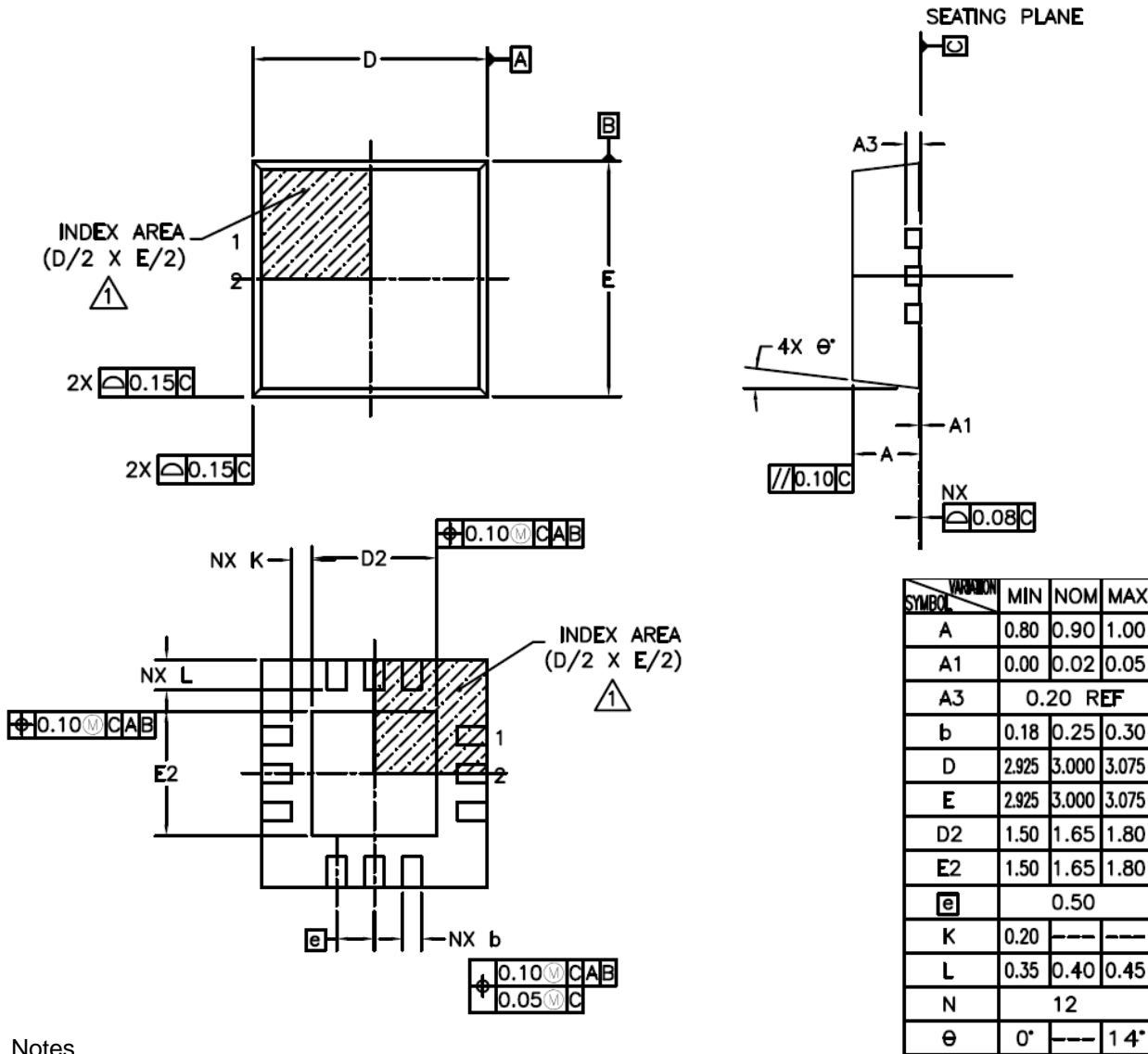


Isolation



HRF-SW1000

PACKAGE OUTLINE DRAWING



Notes

- Pin 1 identifier can be a combination or a dot and/or chamfer. A chamfer is on the bottom ground plane.
- Dimensions are in millimeters.

HALOGEN-FREE MATERIAL SET

The -FL switches have a Halogen-free material set that can withstand a maximum soldering temperature of 260°C.

LEAD FINISH

The package leads are Nickel Palladium with a Gold and Silver flash (NiPdAu+Ag). The configuration being manufactured and delivered today is lead-free and RoHS compliant. Plating thicknesses are listed below in microns (um).

Ni = 0.254 um min	Pd = 0.00254 um min	Au+Ag = 0.00508 um min	Au Composition = 30% min to 70% max
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LEAD FREE QFN SURFACE MOUNT APPLICATION

Please see Application Note AN310a for assembly process recommendations. The maximum soldering temperature of the -FL is 260°C. Application Notes can be found at our website: www.honeywell.com/microwave

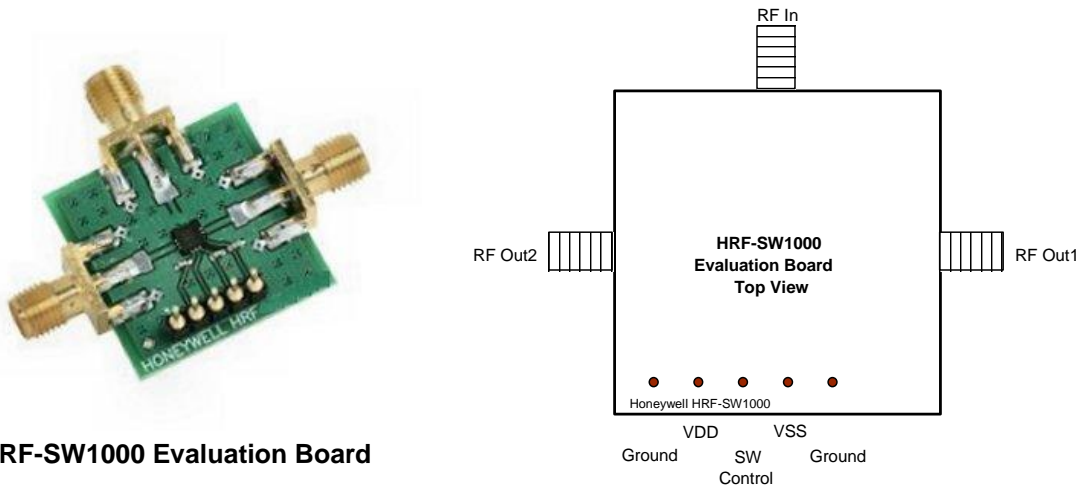
CIRCUIT APPLICATION INFORMATION

These switches require a DC reference to ground. They may not operate properly when AC coupled on both the RF input and output without a DC ground reference provided as part of the circuit. See Application Note AN311.

HRF-SW1000

EVALUATION CIRCUIT BOARD

Honeywell's evaluation board provides an easy to use method of evaluating the RF performance of our switch. Simply connect power; DC and RF signals to be measuring switch performance in less than 10 minutes.



HRF-SW1000 Evaluation Board

EVALUATION CIRCUIT BOARD LAYOUT DESIGN DETAILS

Item	Description
PCB	Impedance Matched Multi-Layer FR4
Switch	HRF-SW1000 RF Switch
Chip Capacitor	Panasonic Model ECU-E1C103KBQ Capacitor, .01uf 0402 10% 16V
RF Connector	Johnson Connectors Model 142-0701-801 SMA RF Coaxial Connector
DC Pin	Mil-Max Model 800-10-064-10-001 Header Pins

ORDERING INFORMATION

Ordering Number	Delivery Method	Units Per Shipment
HRF-SW1000-FL-TR HRF-SW1000-E	Tape & Reel Evaluation Board	2500 Units per Reel One Board Per Box

The new –FL switches replace and are electrically equivalent with the –GR switches. The –GR switches are obsolete.

FIND OUT MORE

For more information on Honeywell’s Microwave Products visit us online at www.honeywellmicrowave.com or contact us at 800-323-8295 (763-954-2474 internationally).

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